# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



# GP2S40J0000F

**Detecting Distance : 3mm** Phototransistor Output, **Compact Reflective Photointerrupter** 



#### Description

GP2S40J0000F is a compact-package, phototransistor output, reflective photointerrupter, with emitter and detector facing the same direction in a molding that provides non-contact sensing. The compact package series is a result of unique technology, combing transfer and injection molding, that also blocks visible light to minimize false detection.

This device has a long focal distance for this family of devices.

#### Features

- 1. Reflective with Phototransistor Output
- 2. Highlights :
- Compact Size
- 3. Key Parameters :
  - Optimal Sensing Distance : 3mm
  - Package : 4×3×2.4mm
  - Visible light cut resin to prevent
- 4. Lead free and RoHS directive compliant

#### Agency approvals/Compliance

1. Compliant with RoHS directive

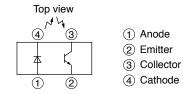
#### Applications

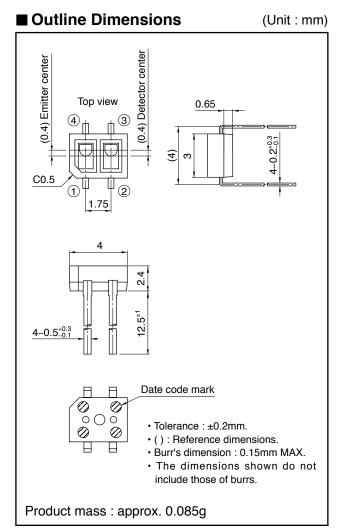
- 1. Detection of object presence or motion.
- 2. Example : printer, optical storage

Notice The content of data sheet is subject to change without prior notice. In the absence of confirmation by device specification sheets, SHARP takes no responsibility for any defects that may occur in equipment using any SHARP devices shown in catalogs, data books, etc. Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device.



#### ■ Internal Connection Diagram





Plating material : SnCu (Cu : TYP. 2%)

## HARP

## Date code (Symbol)

#### January













April	







Nov	em	ber

Π Π

October



June



Decer	nber	



Country of origin Japan

#### July



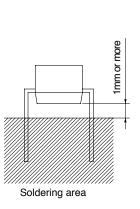






## IARP

■ Absolute Maximum Ratings (T <sub>a</sub> =25°				(T <sub>a</sub> =25°C)
	Parameter	Symbol	Rating	Unit
	Forward current	IF	50	mA
Input	Reverse voltage	V <sub>R</sub>	6	V
	Power dissipation	PD	75	mW
	Collector-emitter voltage	V <sub>CEO</sub>	35	V
Output	Emitter-collector voltage	V <sub>ECO</sub>	6	V
	Collector current	I <sub>C</sub>	20	mA
	Collector power dissipation	P <sub>C</sub>	75	mW
Total power dissipation		P <sub>tot</sub>	100	mW
Operating temperature		T <sub>opr</sub>	-25 to +85	°C
Storage temperature		T <sub>stg</sub>	-40 to +100	°C
<sup>*1</sup> Soldering temperature		T <sub>sol</sub>	260	°C



\*1 For 5s

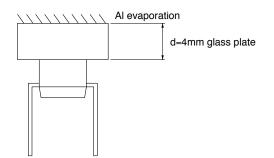
#### Electro-optical Characteristics

 $(T_a=25^{\circ}C)$ TYP. Parameter Symbol Condition MIN. MAX. Unit I<sub>F</sub>=20mA Forward voltage  $V_{\rm F}$ 1.2 1.4 V \_ Input Reverse current  $V_R=3V$ 10 μΑ  $I_R$ \_ \_ Output Collector dark current V<sub>CE</sub>=20V 1 100  $I_{\text{CEO}}$ nA \_ <sup>\*2</sup> Collector Current  $I_F=20mA, V_{CE}=5V$ 3 0.5 mА  $I_{C}$ \_ Transfer \*3 Leak current  $I_F=20mA, V_{CE}=5V$  $I_{\text{LEAK}}$ 500 nA \_ \_ charac-150  $V_{CE}=2V, I_{C}=100\mu A,$ 50 Rise time \_  $t_r$ teristics Response time μs Fall time  $R_L=1k\Omega$ , d=4mm 50 150  $t_{\rm f}$ \_

\*2 The condition and arrangement of the reflective object are shown below.

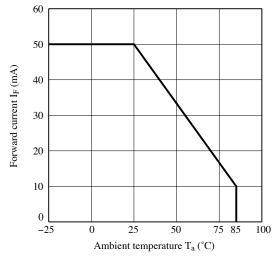
\*3 No reflective object

### • Test Arrangement for Collector Current

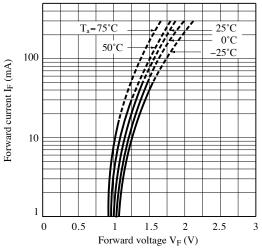




### Fig.1 Forward Current vs. Ambient Temperature









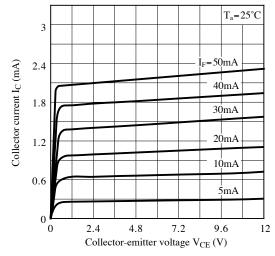
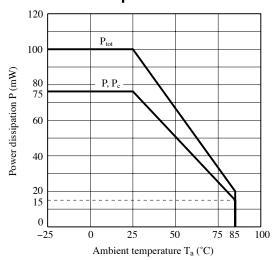
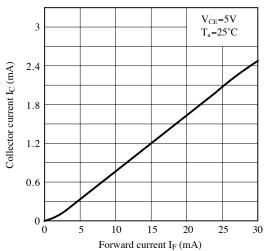


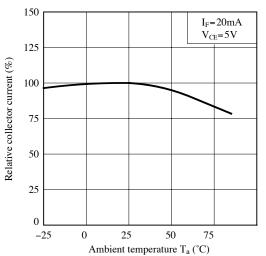
Fig.2 Collector Power Dissipation vs. Ambient Temperature



#### Fig.4 Collector Current vs. Forward Current

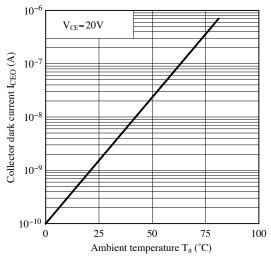


#### Fig.6 Relative Collector Current vs. Ambient Temperature

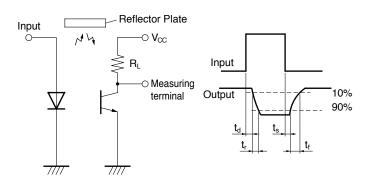




#### Fig.7 Collector Dark Current vs. Ambient Temperature



#### Fig.9 Test Circuit for Response Time



#### Fig.11 Detecting Position Characteristics (2)

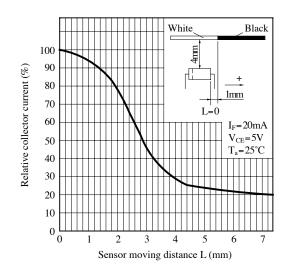
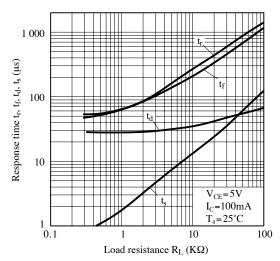


Fig.8 Response Time vs. Load Resistance



#### Fig.10 Detecting Position Characteristics (1)

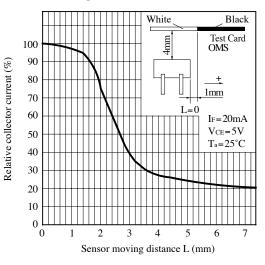
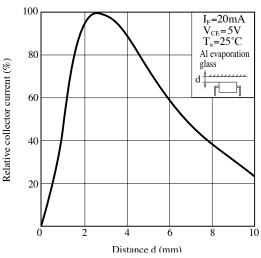


Fig.12 Relative Collector Current vs. Distance (Reference value)



Remarks : Please be aware that all data in the graph are just for reference and not for guarantee.



#### ■ Design Considerations

#### Design guide

1) Prevention of detection error

To prevent photointerrupter from faulty operation caused by external light, do not set the detecting face to the external light.

2) Distance characteristic

Please refer to Fig.12 (Relative collector current vs. Distance) to set the distance of the photointerrupter and the object.

This product is not designed against irradiation and incorporates non-coherent IRED.

#### Degradation

In the case of long term operation, please take the general IRED degradation (50% degradation over 5 years) into the design consideration.

#### Parts

This product is assembled using the below parts.

#### • Photodetector (qty. : 1)

Category	Material	Maximum Sensitivity wavelength (nm)	Sensitivity wavelength (nm)	Response time (µs)
Phototransister	Silicon (Si)	930	700 to 1 200	20

#### • Photo emitter (qty. : 1)

Category	Material	Maximum light emitting wavelength (nm)	I/O Frequency (MHz)
Infrared emitting diode (non-coherent)	Gallium arsenide (GaAs)	950	0.3

#### Material

Case	Lead frame	Lead frame plating
Black polyphenylene sulfide resin	42Alloy	SnCu plating



#### Manufacturing Guidelines

#### Soldering Method

Flow Soldering:

Soldering should be completed below 260°C and within 5 s.

Soldering area is 1mm or more away from the bottom of housing.

Please take care not to let any external force exert on lead pins.

Please don't do soldering with preheating, and please don't do soldering by reflow.

#### Other notice

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the cooling and soldering conditions.

#### • Cleaning instructions

Solvent cleaning :

Solvent temperature should be 45°C or below. Immersion time should be 3 minutes or less.

Ultrasonic cleaning :

Do not execute ultrasonic cleaning.

#### Recommended solvent materials :

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol.

#### • Presence of ODC

This product shall not contain the following materials. And they are not used in the production process for this product. Regulation substances : CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.

This product shall not contain the following materials banned in the RoHS Directive (2002/95/EC).
•Lead, Mercury, Cadmium, Hexavalent chromium, Polybrominated biphenyls (PBB), Polybrominated diphenyl ethers (PBDE).



#### Package specification

#### Sleeve package

Package materials Sleeve : Polystyrene Stopper : Styrene-Butadiene

Package method

MAX. 50 pcs. of products shall be packaged in a sleeve. Both ends shall be closed by tabbed and tabless stoppers.

MAX. 20 sleeves in one case.

## SHARP

#### Important Notices

• The circuit application examples in this publication are provided to explain representative applications of SHARP devices and are not intended to guarantee any circuit design or license any intellectual property rights. SHARP takes no responsibility for any problems related to any intellectual property right of a third party resulting from the use of SHARP's devices.

• Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device. SHARP reserves the right to make changes in the specifications, characteristics, data, materials, structure, and other contents described herein at any time without notice in order to improve design or reliability. Manufacturing locations are also subject to change without notice.

• Observe the following points when using any devices in this publication. SHARP takes no responsibility for damage caused by improper use of the devices which does not meet the conditions and absolute maximum ratings to be used specified in the relevant specification sheet nor meet the following conditions:

(i) The devices in this publication are designed for use in general electronic equipment designs such as:

- --- Personal computers
- --- Office automation equipment
- --- Telecommunication equipment [terminal]
- --- Test and measurement equipment
- --- Industrial control
- --- Audio visual equipment
- --- Consumer electronics

(ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection with equipment that requires higher reliability such as:

- --- Transportation control and safety equipment (i.e., aircraft, trains, automobiles, etc.)
- --- Traffic signals
- --- Gas leakage sensor breakers
- --- Alarm equipment
- --- Various safety devices, etc.

(iii) SHARP devices shall not be used for or in connection with equipment that requires an extremely high level of reliability and safety such as:

- --- Space applications
- --- Telecommunication equipment [trunk lines]
- --- Nuclear power control equipment
- --- Medical and other life support equipment (e.g., scuba).

• If the SHARP devices listed in this publication fall within the scope of strategic products described in the Foreign Exchange and Foreign Trade Law of Japan, it is necessary to obtain approval to export such SHARP devices.

• This publication is the proprietary product of SHARP and is copyrighted, with all rights reserved. Under the copyright laws, no part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, for any purpose, in whole or in part, without the express written permission of SHARP. Express written permission is also required before any use of this publication may be made by a third party.

 $\cdot$  Contact and consult with a SHARP representative if there are any questions about the contents of this publication.